

# MID SEMESTER EVALUATION

## RESEARCH AND DEVELOPMENT OF HETEROJUNCTION BASED PHOTODETECTOR



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Department of Electrical Engineering  
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**Supervised by**

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**Presented by**

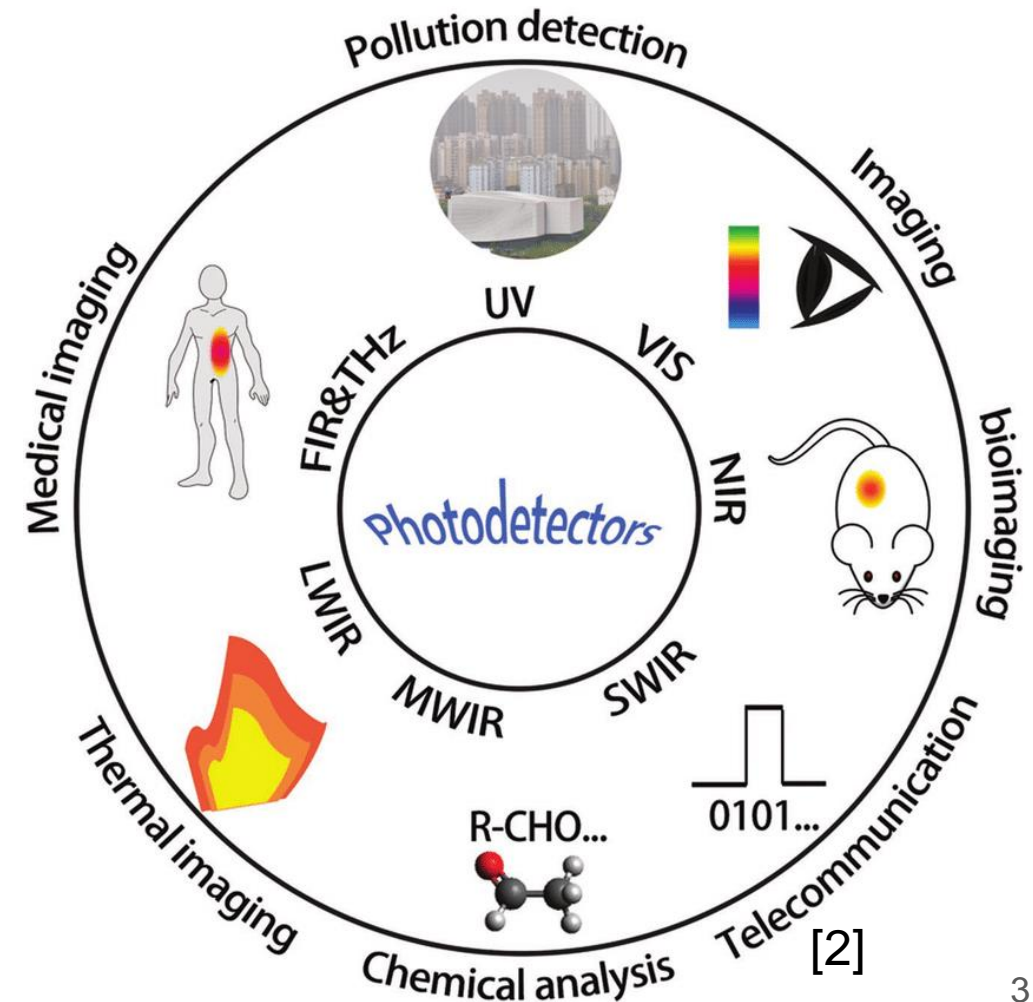
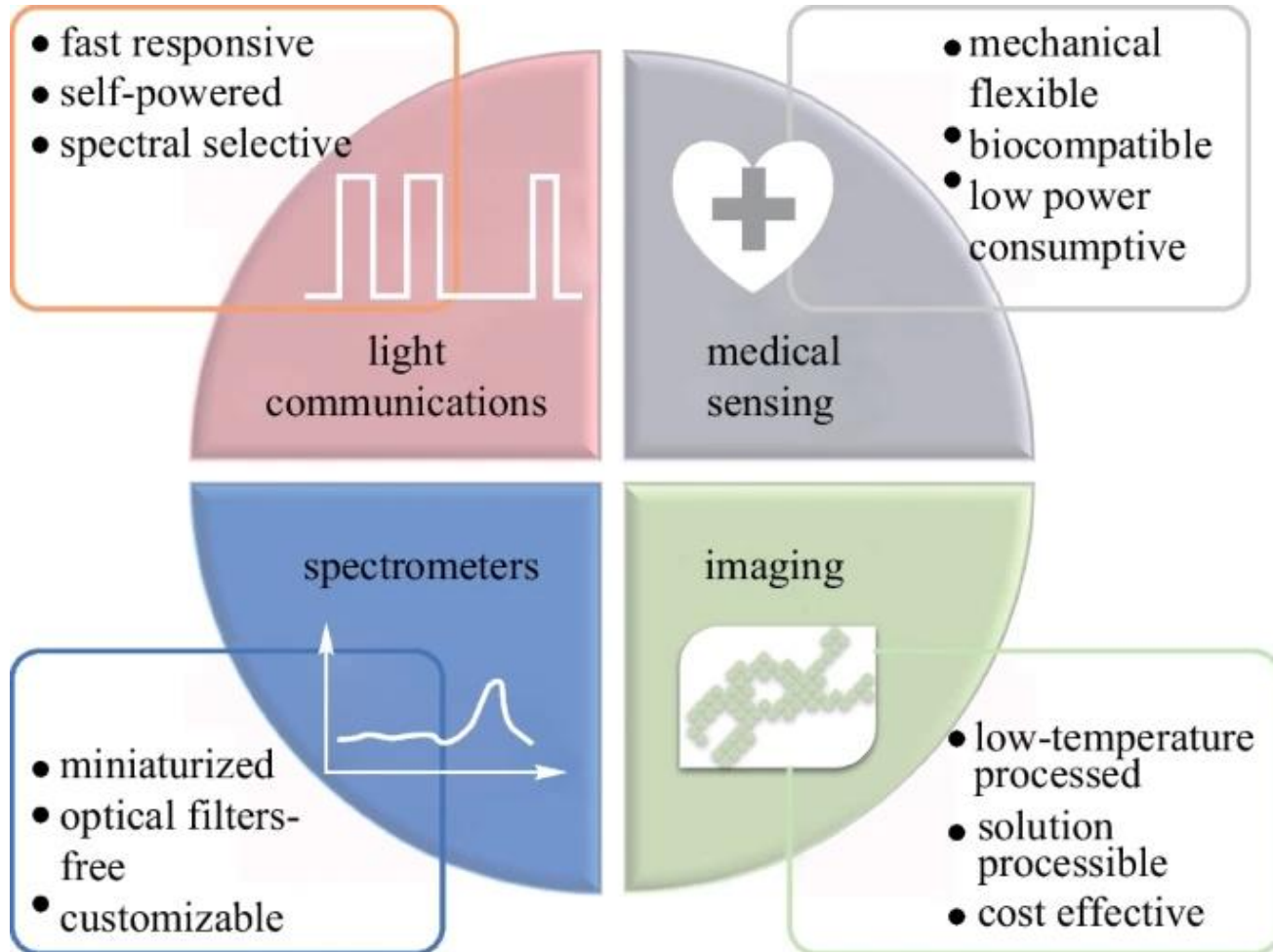
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M.S. Research, IIT Indore

# OUTLINE

- Motivation
- Introduction
- Objective
- Proposed work
  - ZnO Nanostructure growth
  - SEM and UV-Vis. result analysis
  - LSPR and Ag NPs deposition mechanism
  - Ag NPs deposition
  - SEM and UV-Vis. result analysis
  - COMSOL simulation for PVT
- Conclusion
- Plan of action
- Acknowledgements
- References

# MOTIVATION

- Increase in demand of photodetectors

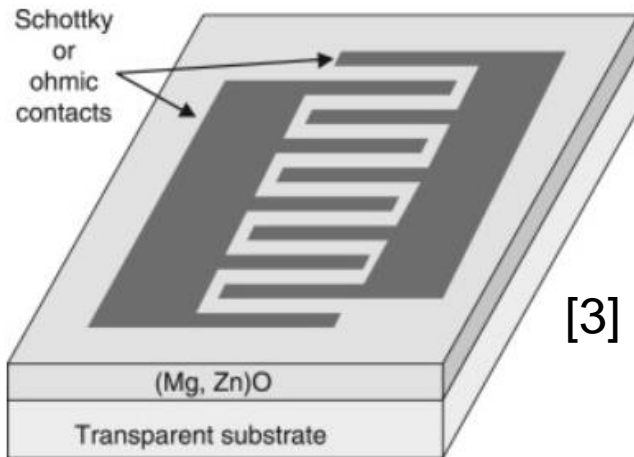


[2]

# INTRODUCTION

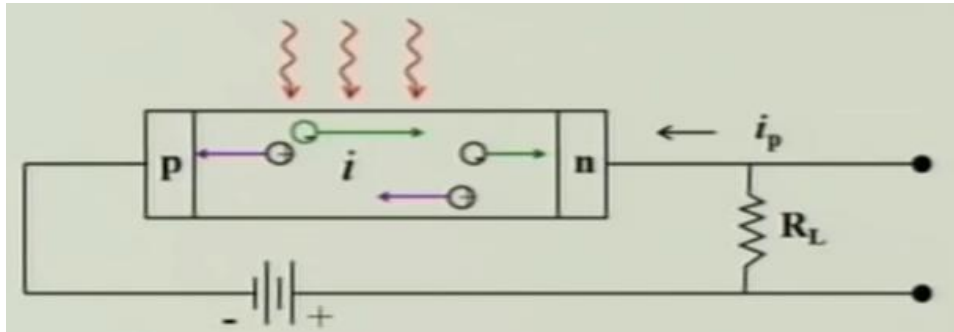
## PHOTODETECTORS

### ➤ Photoconductor



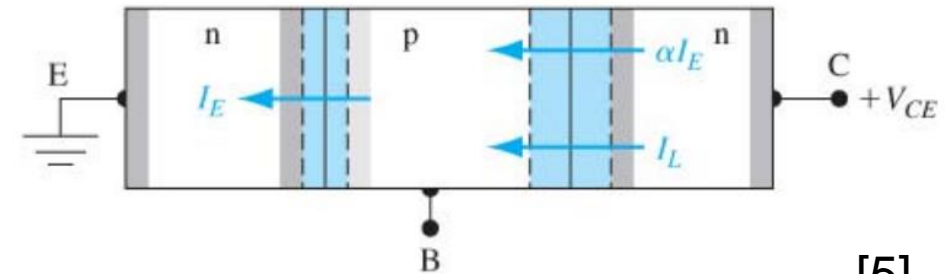
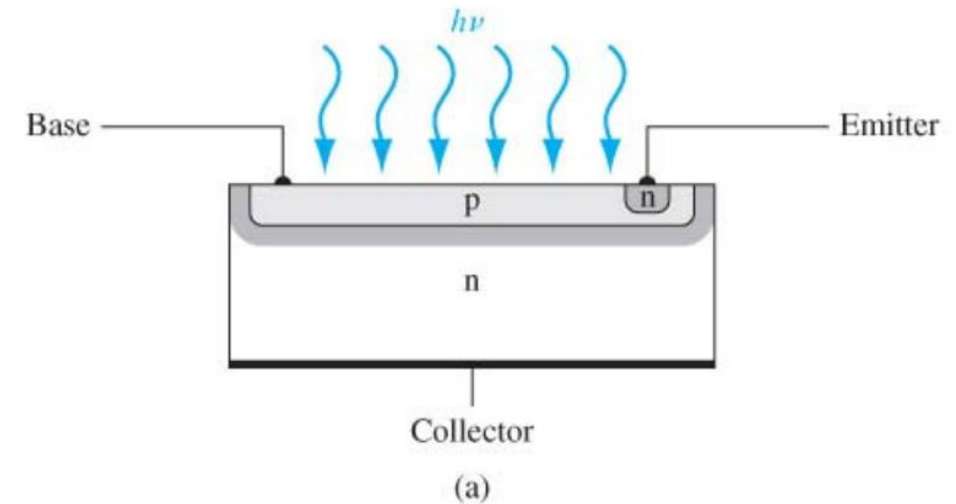
[3]

### ➤ Photodiode



[4]

### ➤ Phototransistor

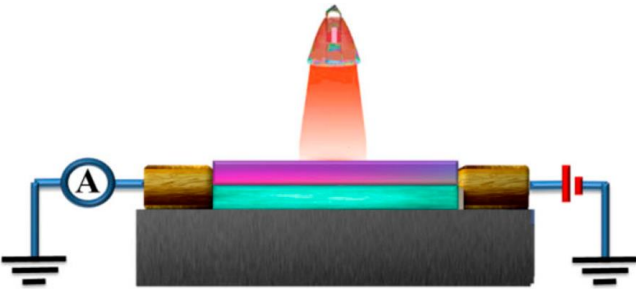


[5]

# HETEROJUNCTION TYPES

Organic - Organic

Phthalocyanine/C<sub>60</sub>



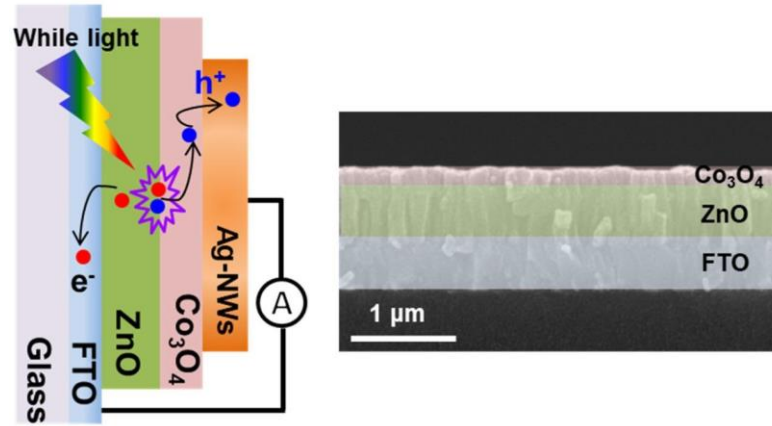
[8]



C<sub>60</sub>

Inorganic - Inorganic

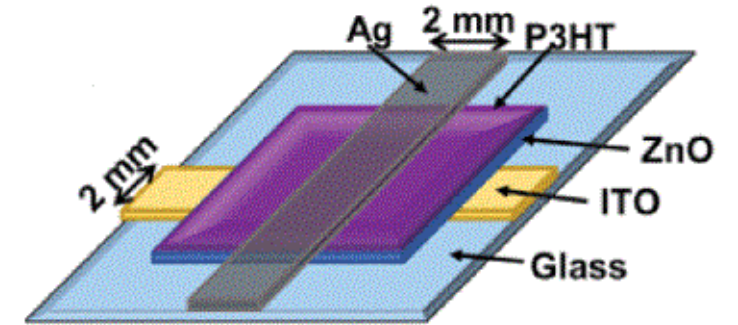
ZnO/Co<sub>3</sub>O<sub>4</sub>



[9]

Organic - Inorganic (Hybrid)

ZnO/P3HT



[10]

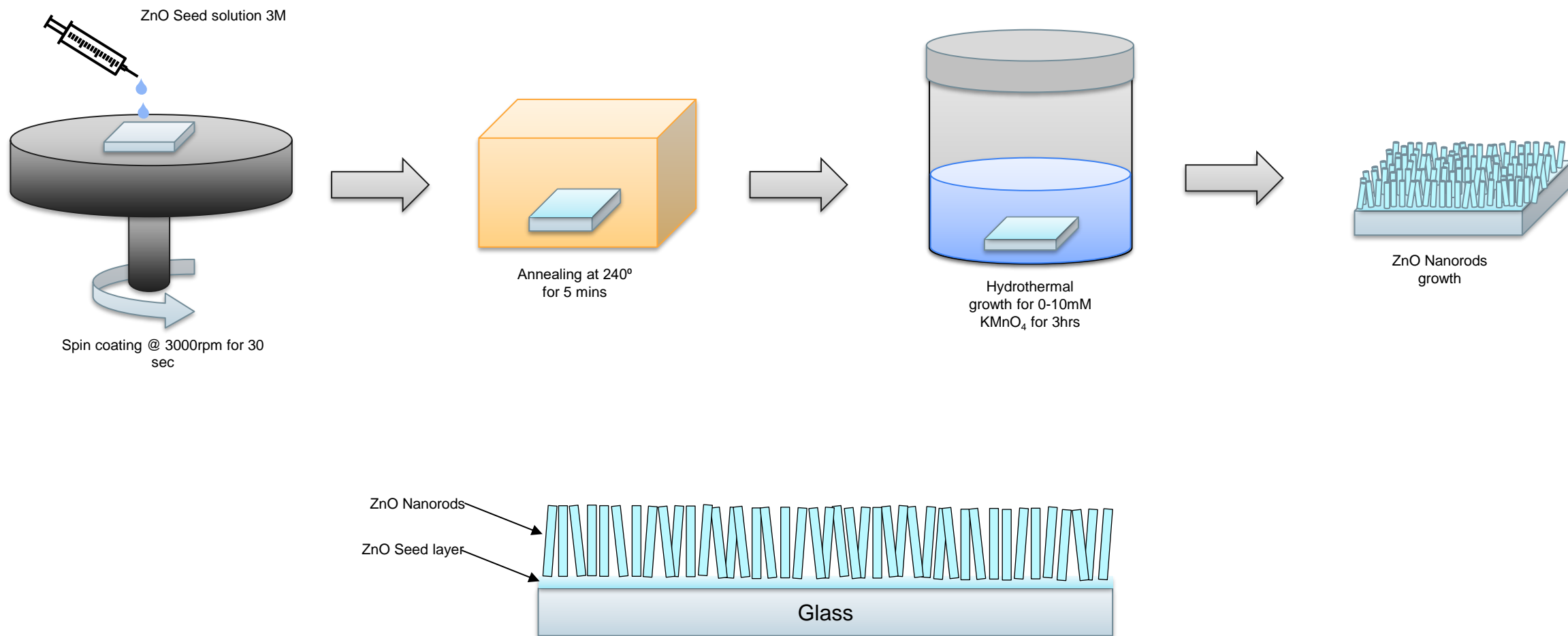
# DEVICE PARAMETERS

Metric	Definition	Unit
Rectification ratio	$\frac{I_{on}}{I_{off}}$	--
Responsivity (R)	$R = \frac{I_{ph}}{P_{in}} = EQE \times \frac{\lambda * q}{h * c}$	AW <sup>-1</sup>
Photosensitivity (S)	$S = \frac{I_{ph} - I_d}{I_d}$	--
Specific Detectivity (D*)	$D^* = \frac{\sqrt{A}}{NEP} = R \times \frac{\sqrt{A \times BW}}{i_{in,N}}$	Jones

# OBJECTIVES

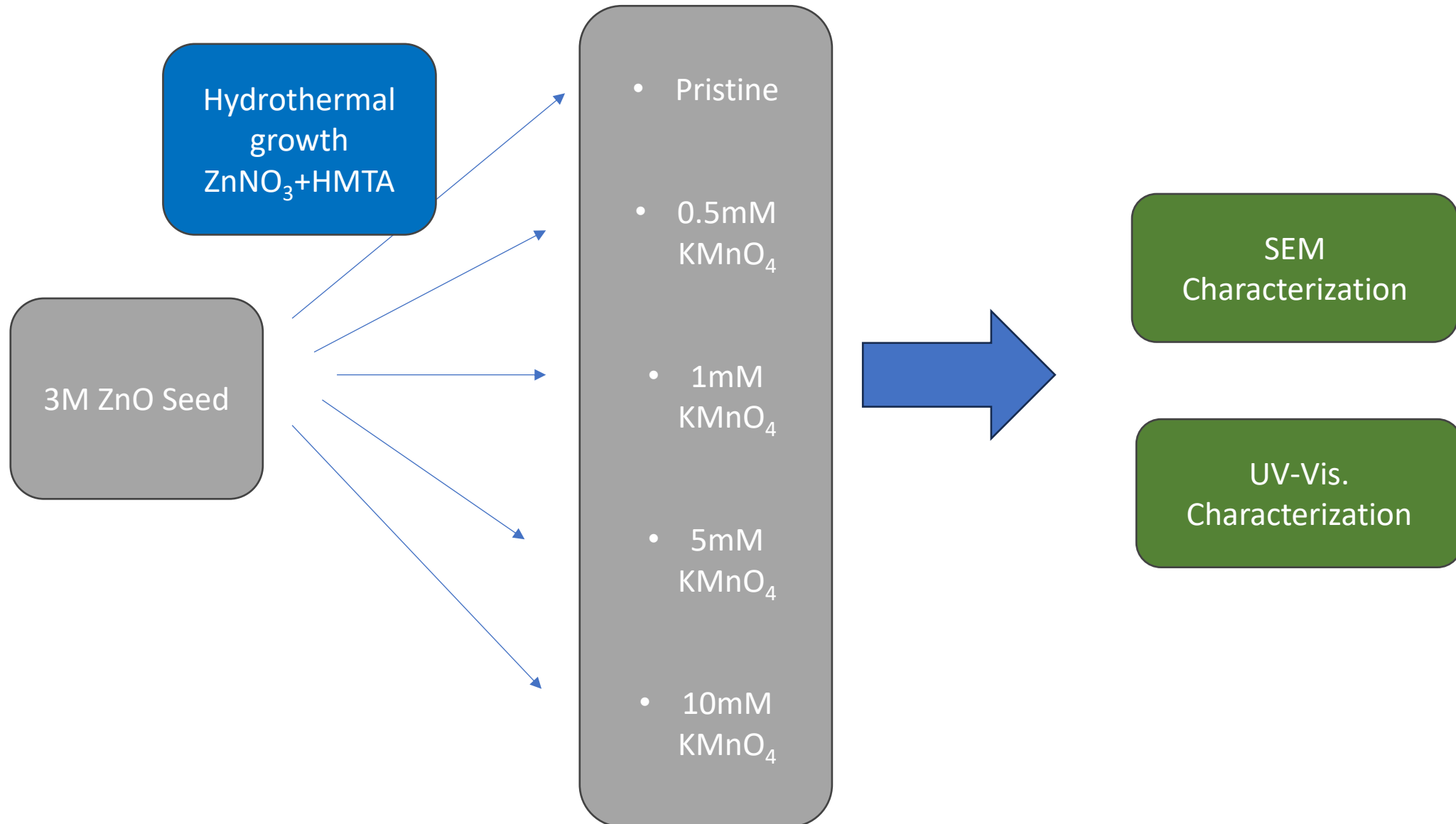
- Fabrication of heterojunction photodetector using solution process.
  - Optimization of various parameters to obtain crystalline growth of ZnO nanorods.
  - Study effect of UV-irradiation time and  $\text{AgNO}_3$ :Ethanol conc. on Ag particle size deposited.
- To study physical vapor transport technique and perform simulation to get optimized parameters.
- Fabrication of heterojunction photodetector using physical vapor transport technique.

# NANOSTRUCTURE GROWTH

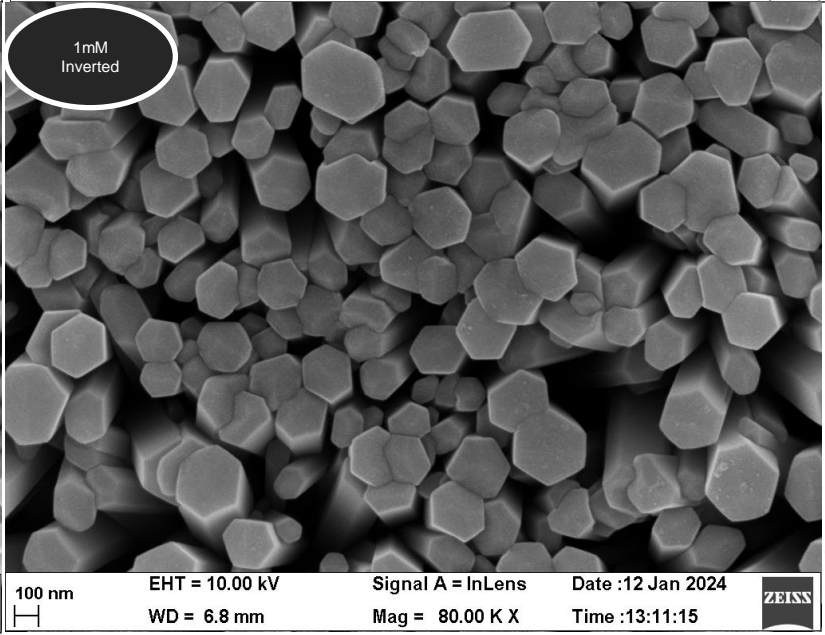
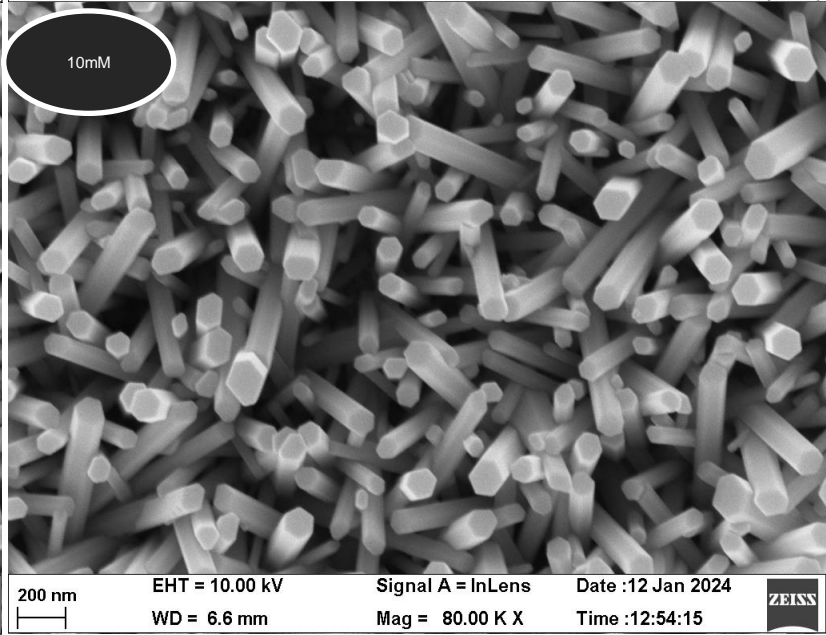
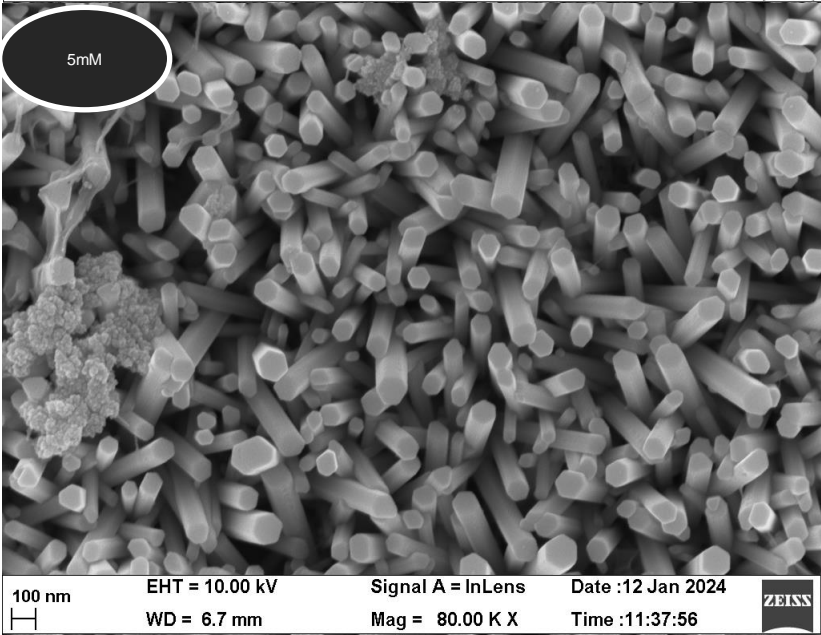
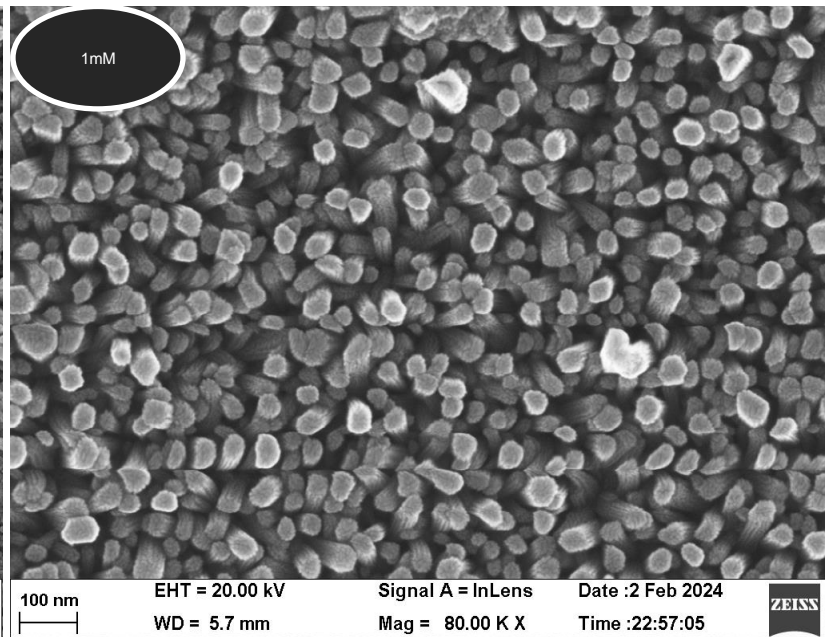
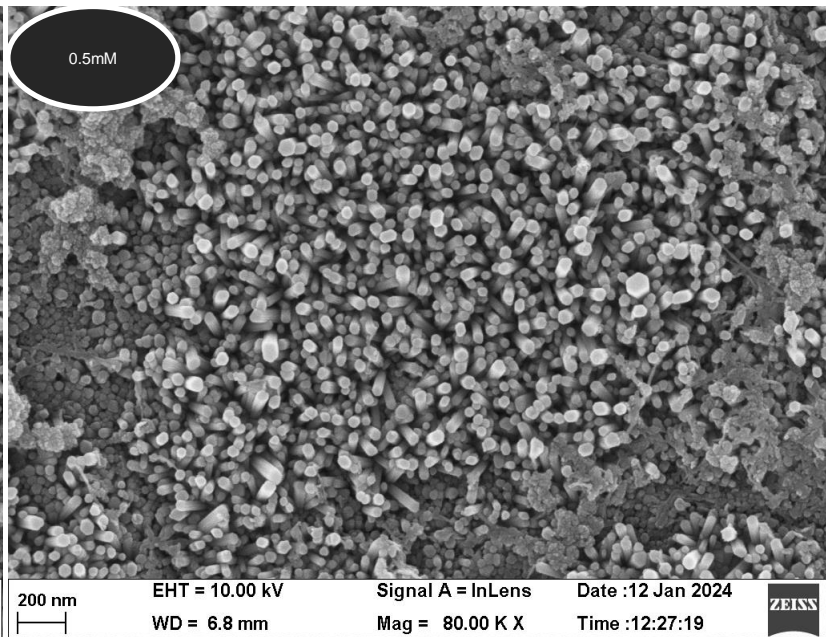
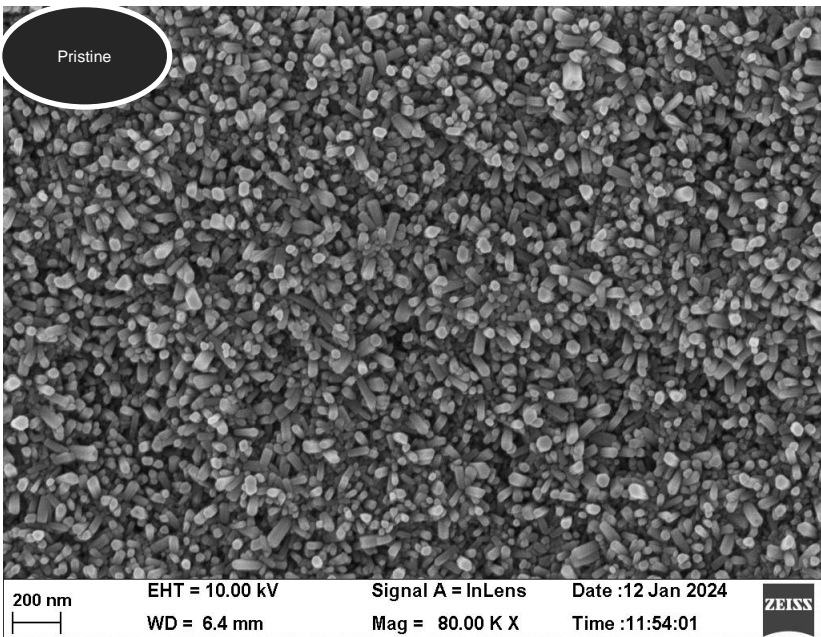




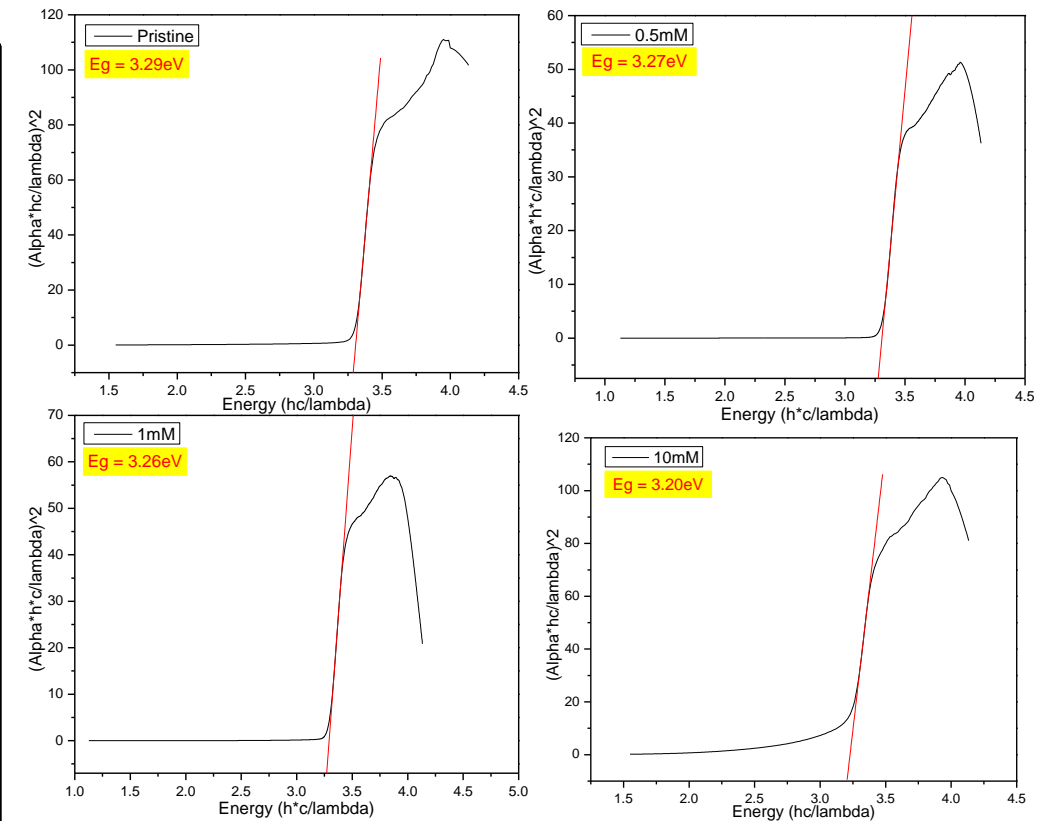
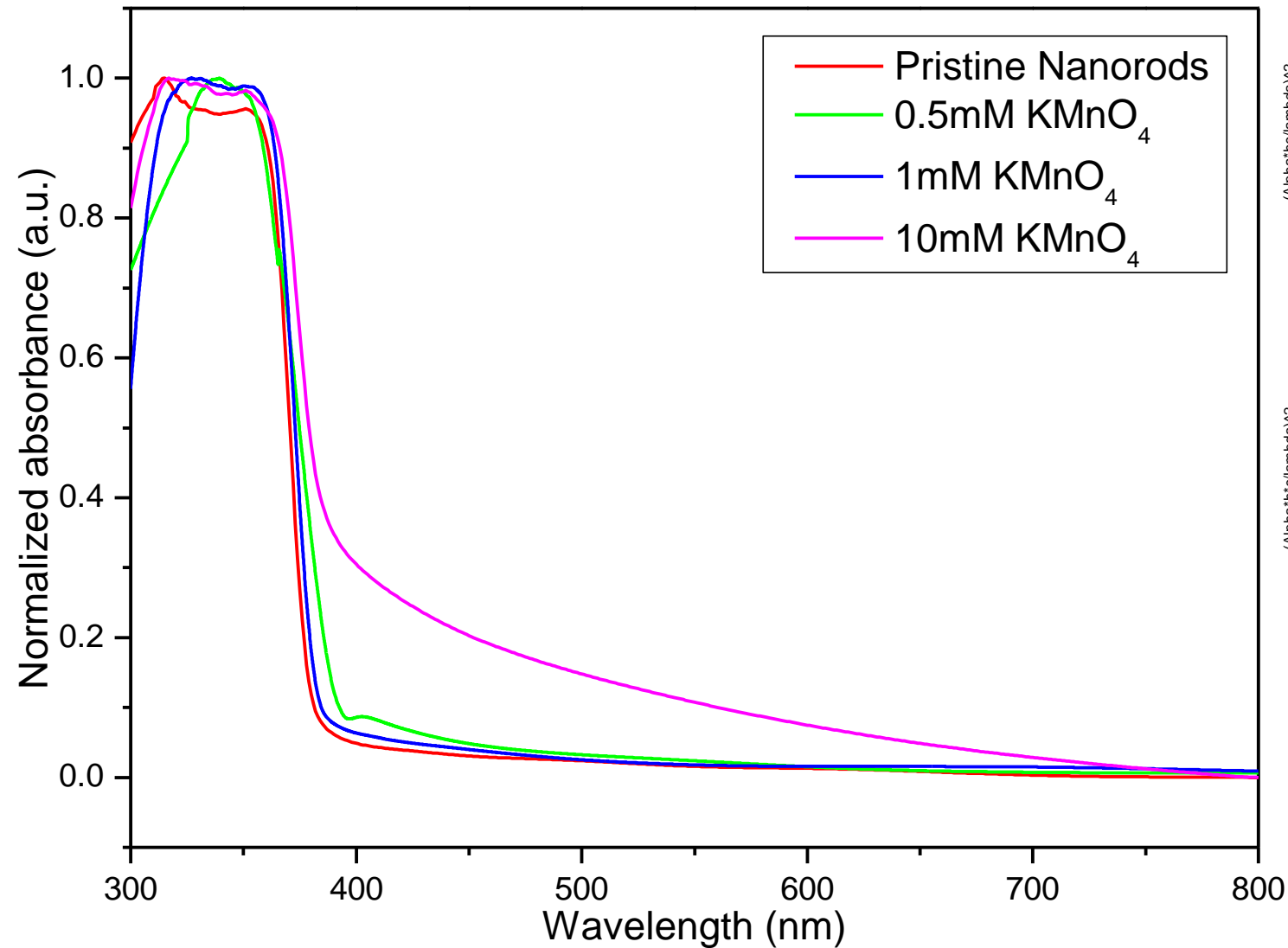
# NANOSTRUCTURE GROWTH



# SEM RESULTS

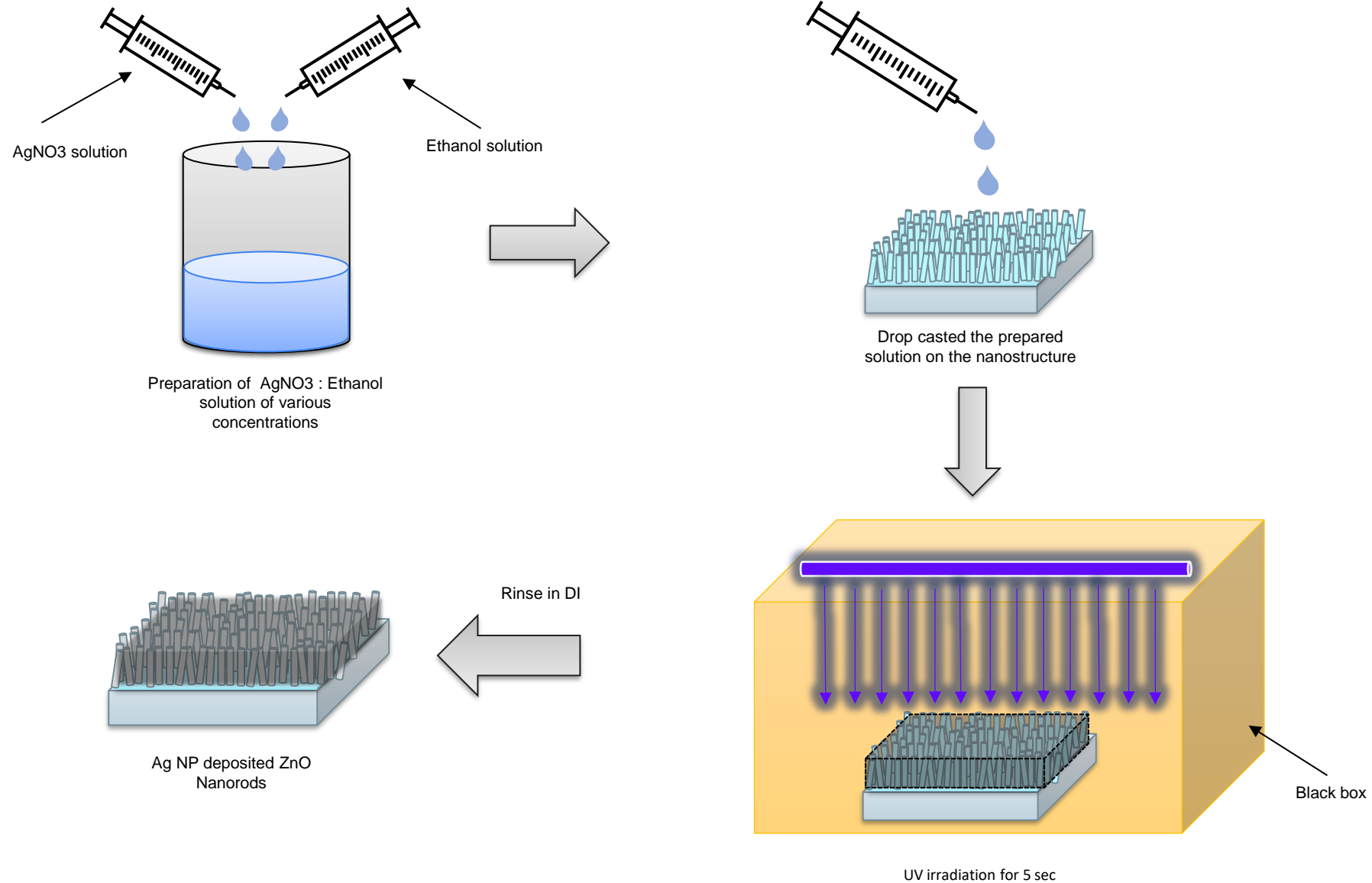


# UV-VIS RESULTS



Sample Details	Bandgap (eV)
Pristine	<b>3.29</b>
<b>0.5mM</b> KMnO <sub>4</sub>	<b>3.27</b>
<b>1mM</b> KMnO <sub>4</sub>	<b>3.26</b>
<b>10mM</b> KMnO <sub>4</sub>	<b>3.2</b>

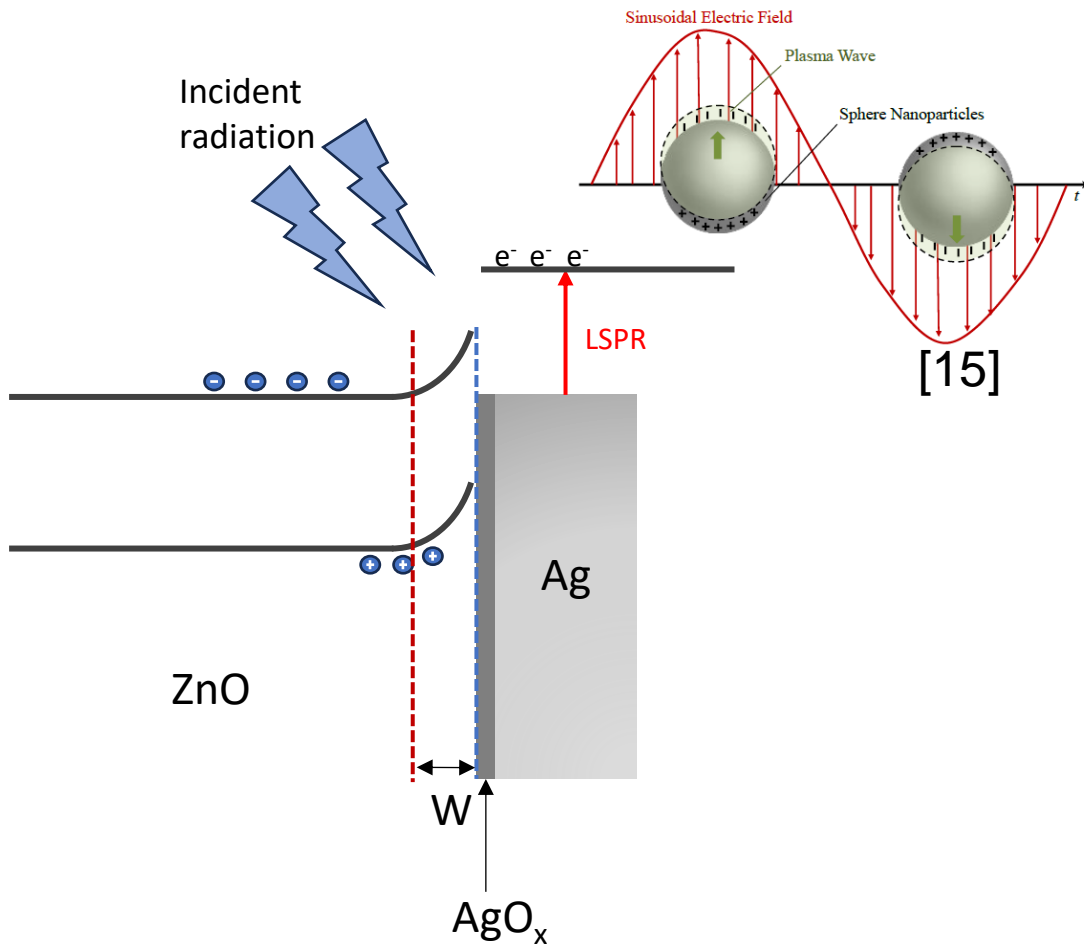
# PCR (PHOTO CHEMICAL REDUCTION)



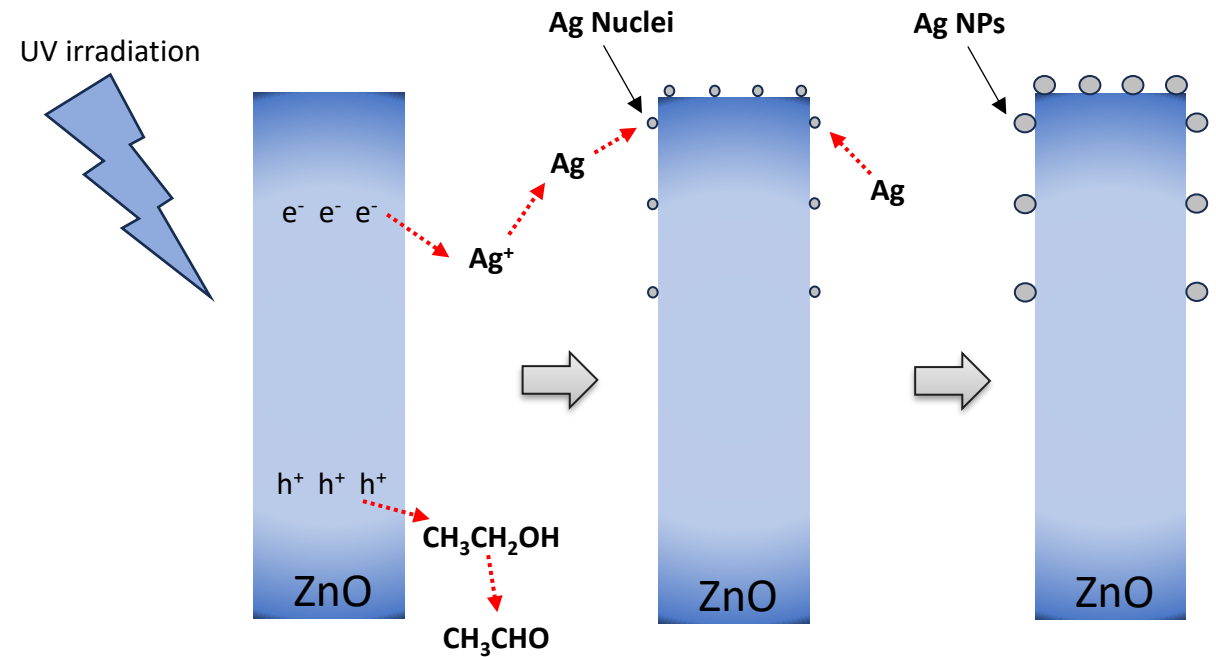


# Localized Surface Plasmonic Resonance

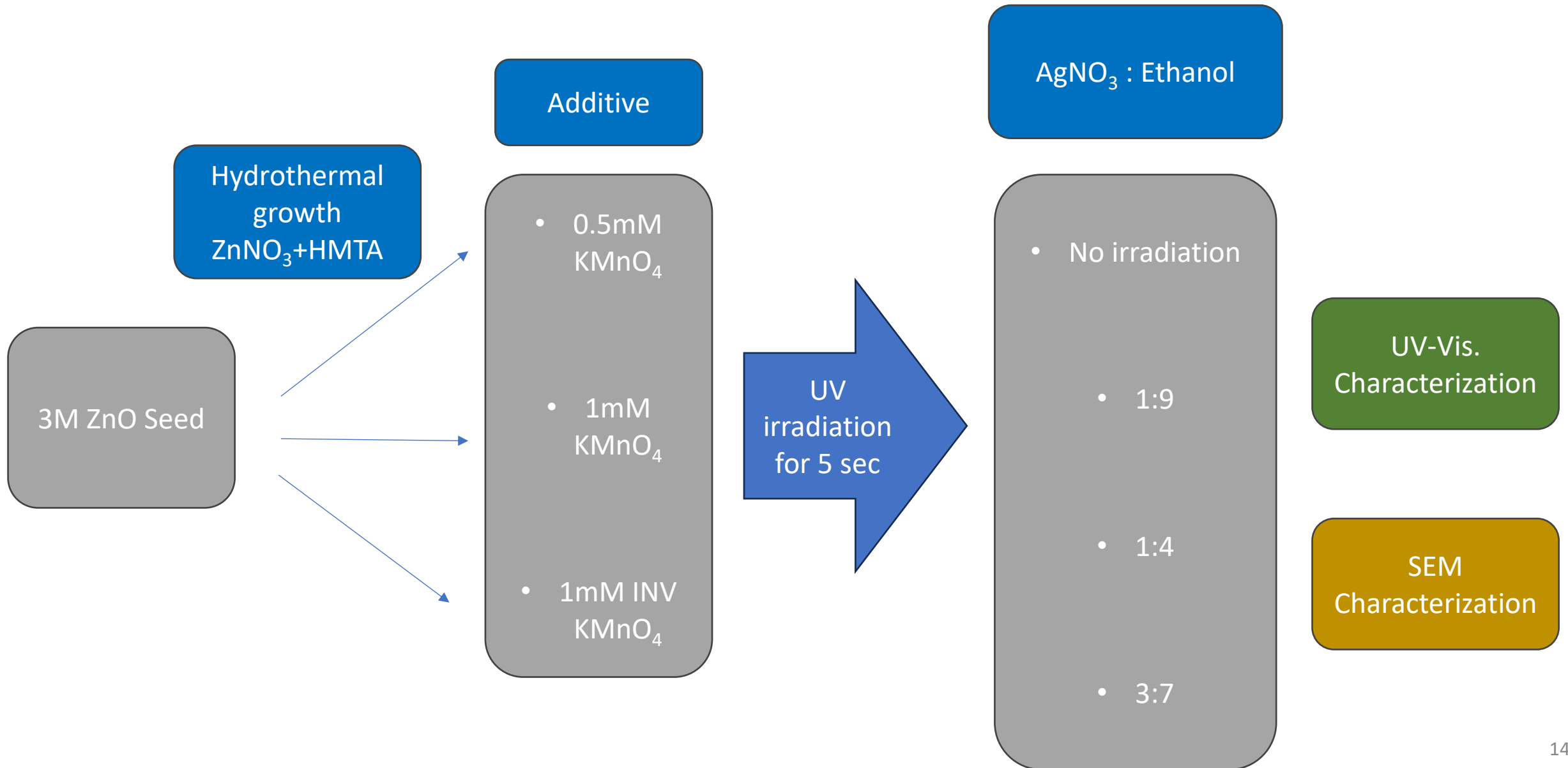
## LSPR effect



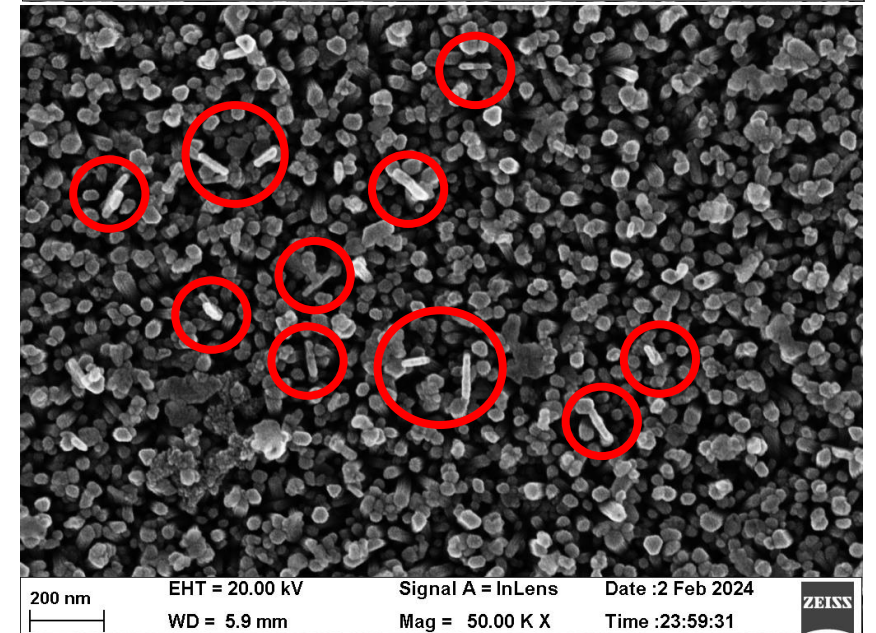
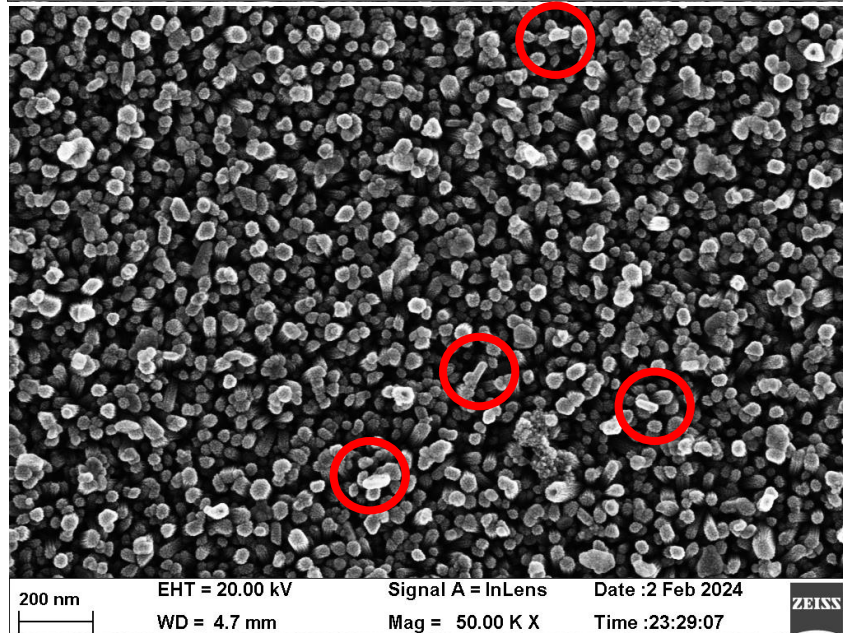
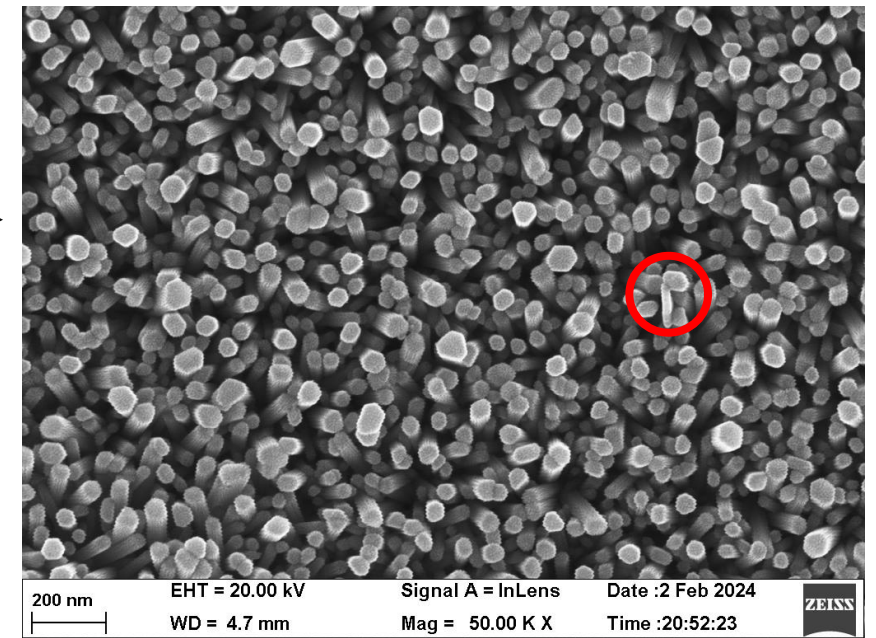
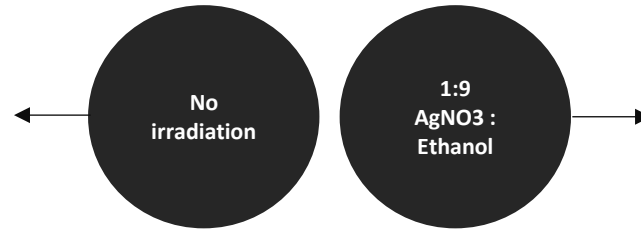
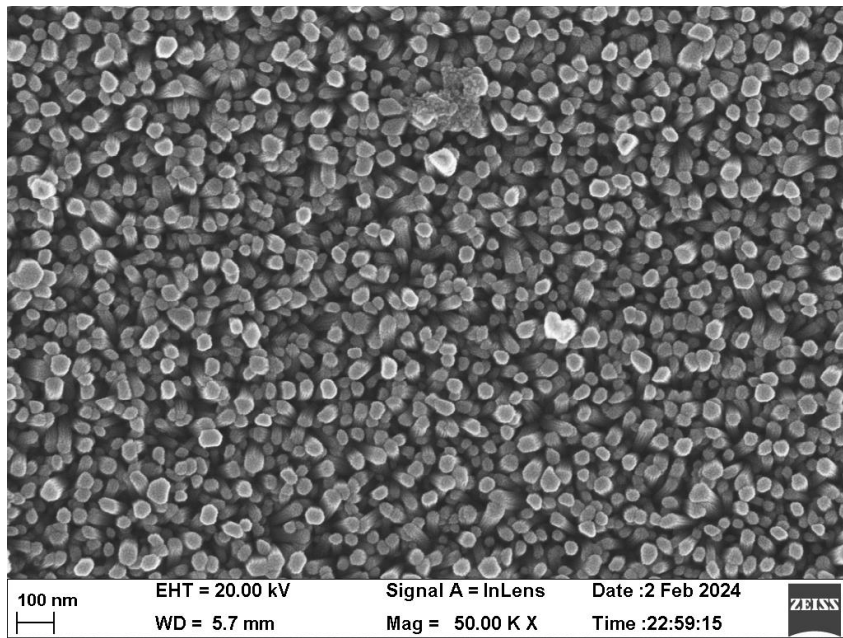
## Ag NPs deposition mechanism



# Ag NP DEPOSITION

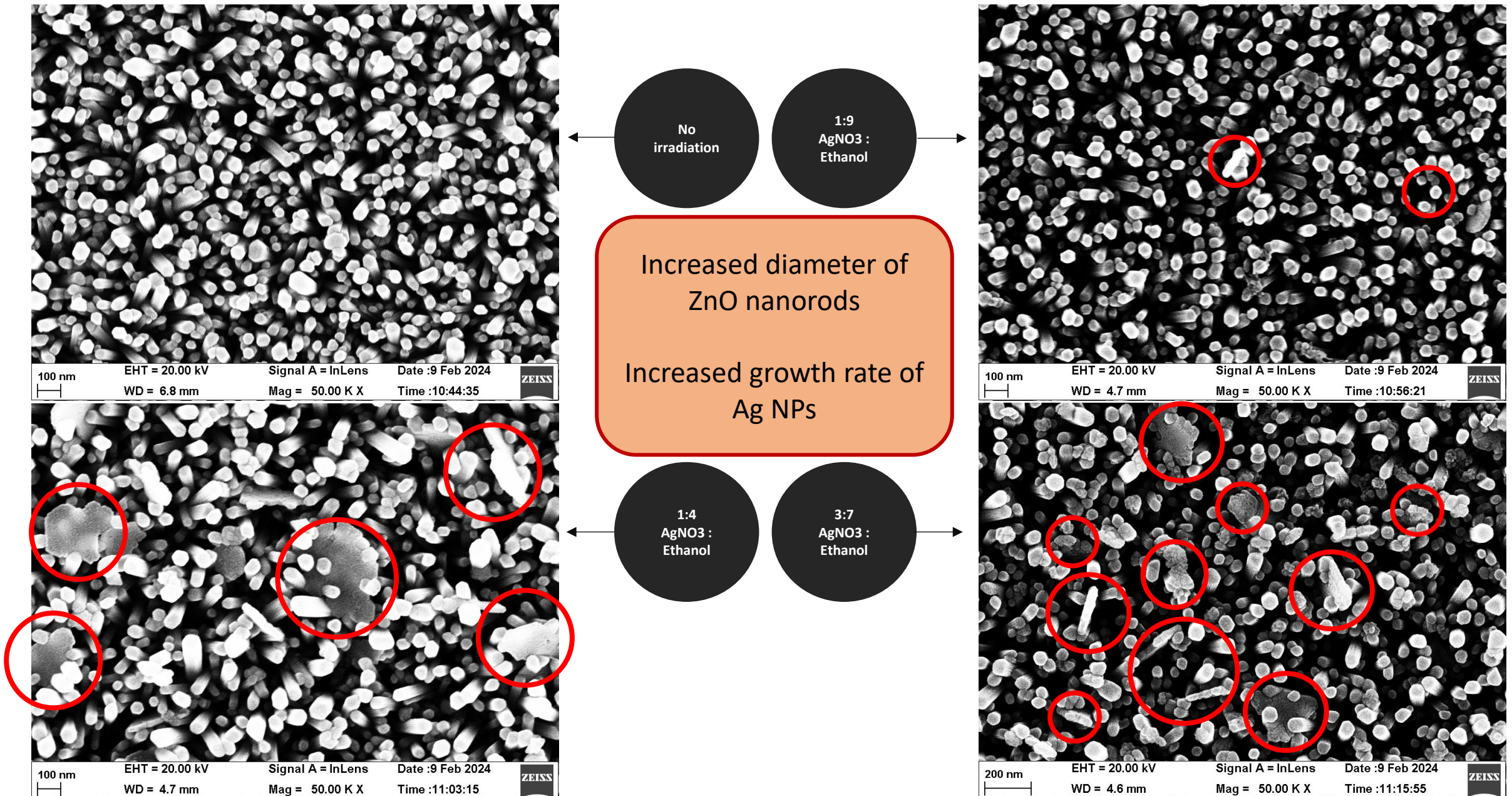


# SEM RESULTS 0.5mM KMnO<sub>4</sub> with Ag NPs



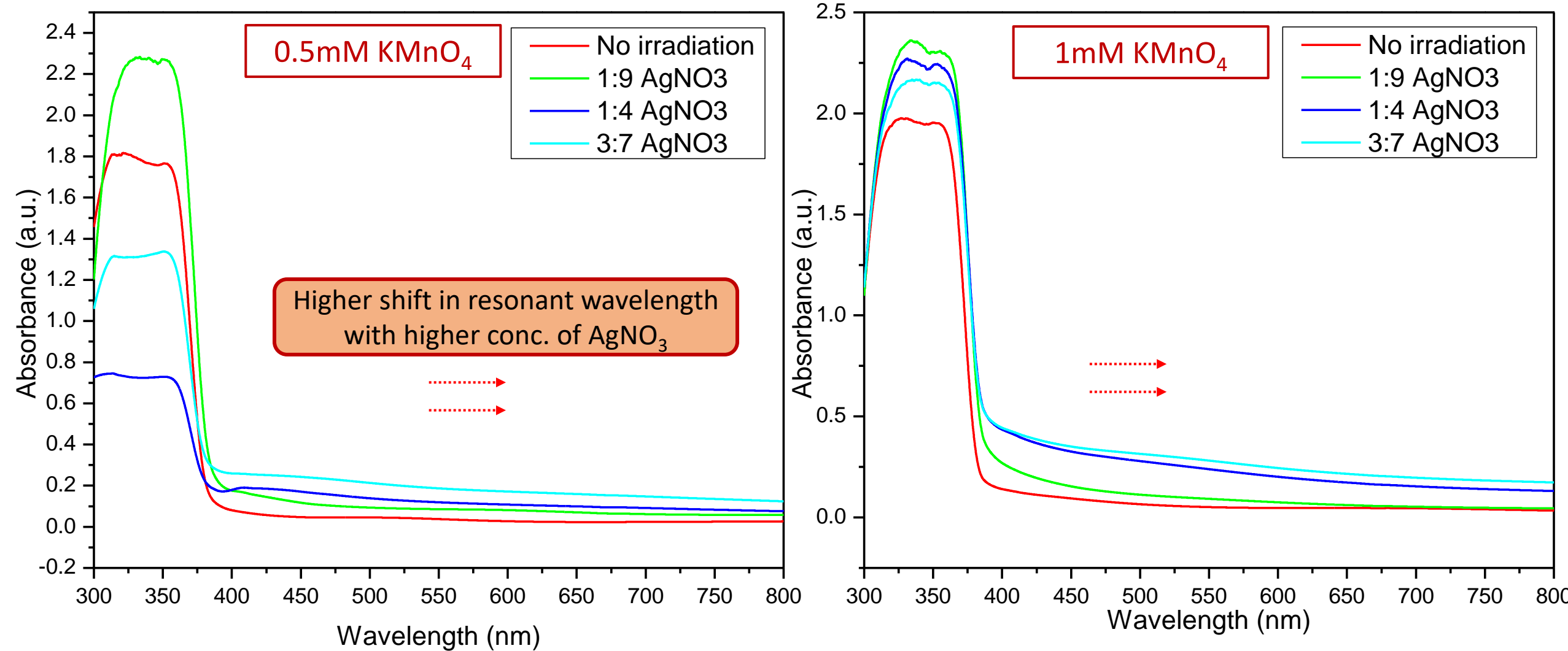


# SEM RESULTS 1mM $\text{KMnO}_4$ with Ag NPs

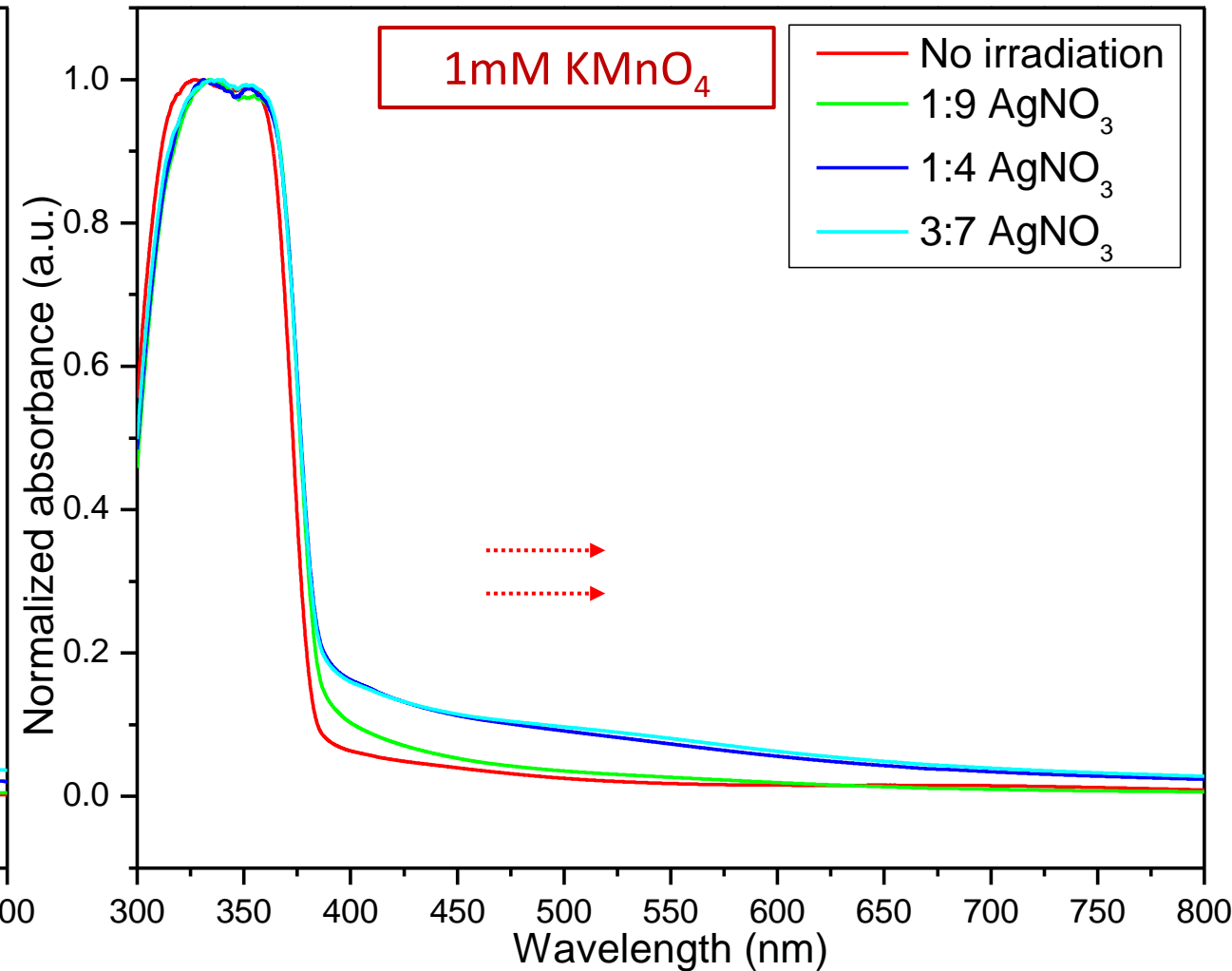
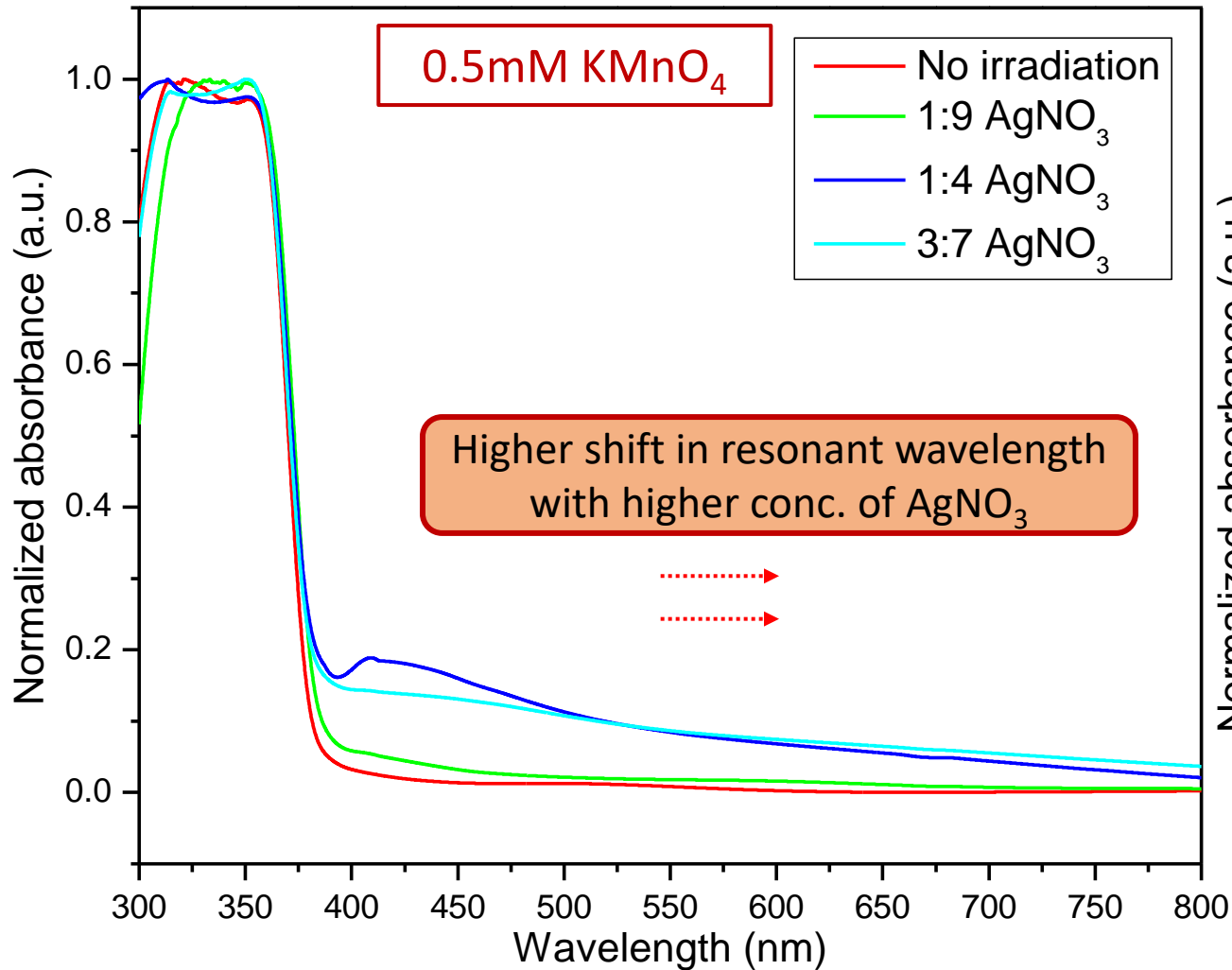




# UV-VIS RESULTS

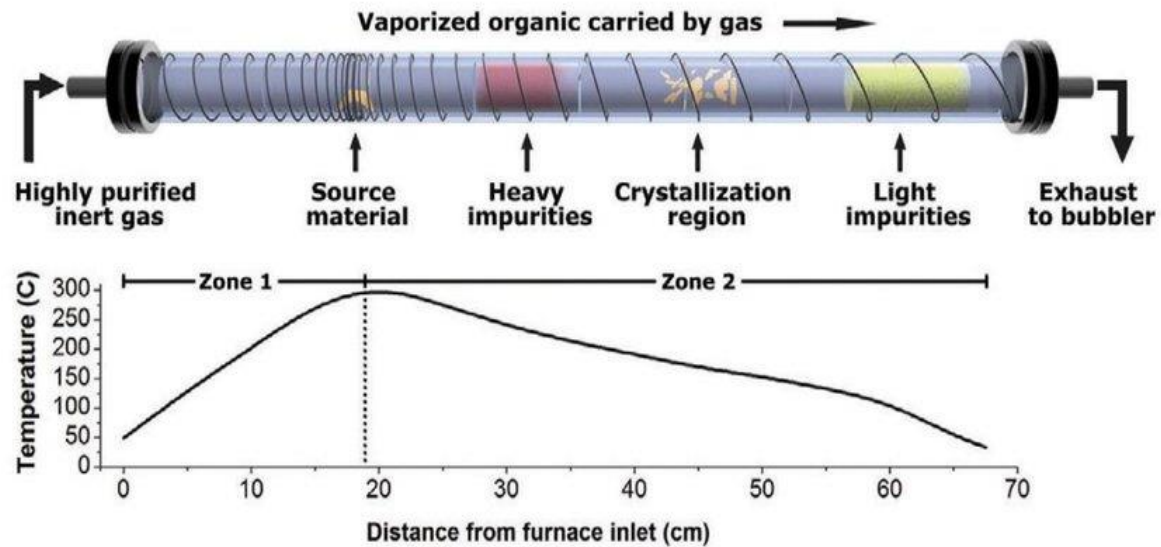


# UV-VIS RESULTS



# Physical Vapour Transport

PVT schematic



[12]

MULTIPHYSICS  
STUDY

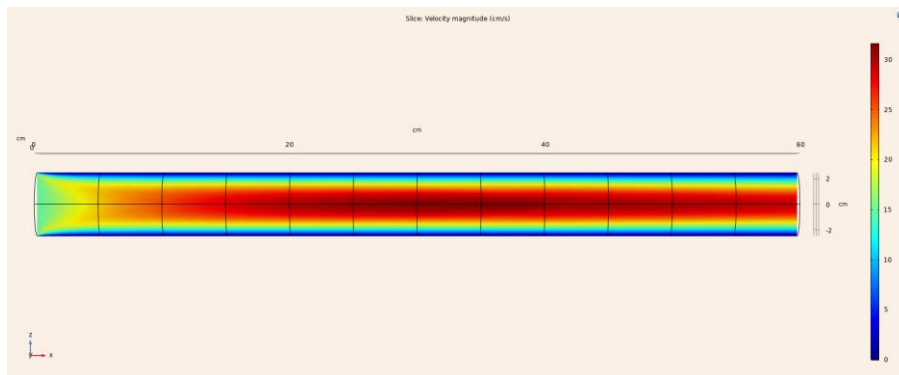
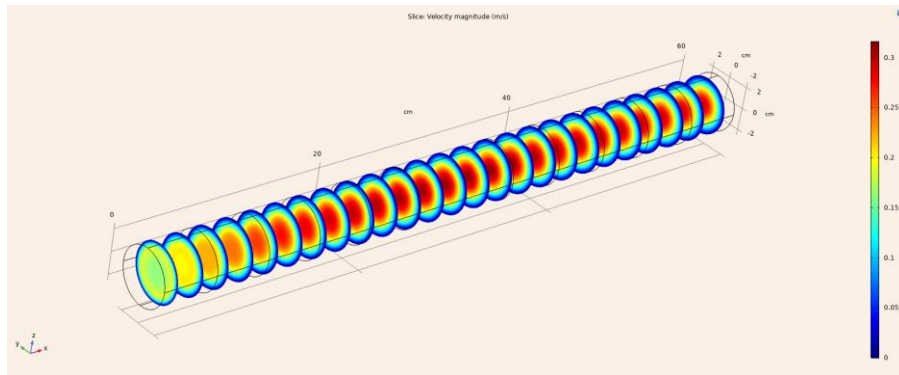
Laminar flow

+

Heat transfer

# COMSOL SIMULATION

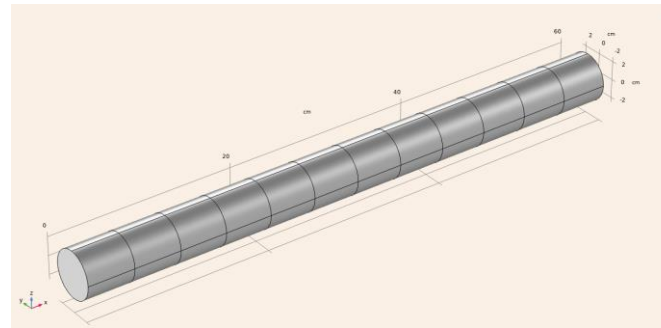
Velocity profile



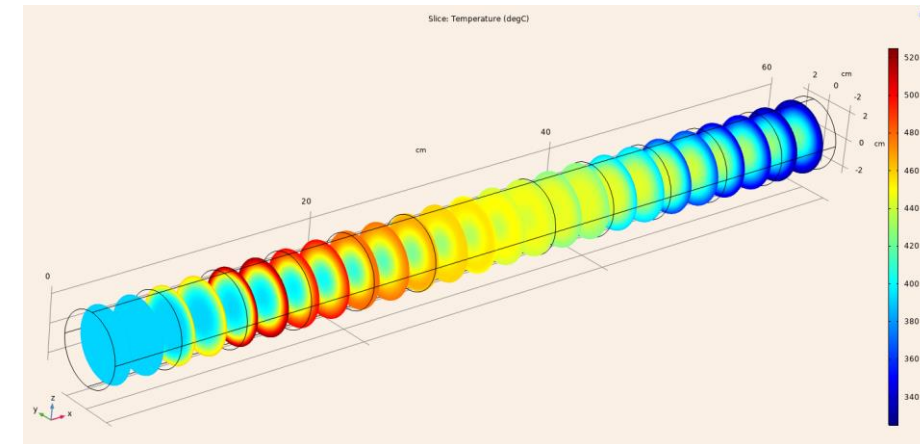
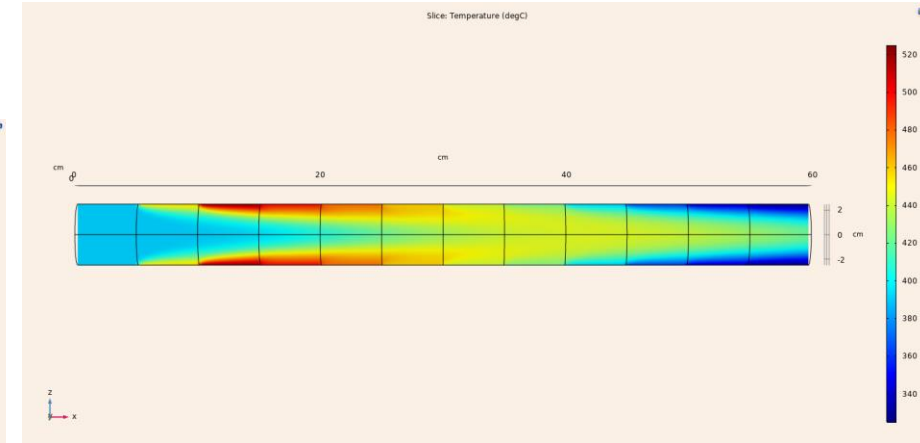
$$U_0 = 15 \text{ cm/s}$$
$$P_0 = 0 \text{ Pa}$$

Defined  
boundary walls  
 $U = 0 \text{ cm/s}$

Geometry



Temperature profile



$$T_0 = t_n \dots n = 1 \text{ to } 12$$

# CONCLUSION

- Synthesized ZnO nanorods using various concentrations of  $\text{KMnO}_4$  additive.
- With increase conc. of  $\text{KMnO}_4$  increase in diameter of nanorods and lower shift in bandgap energy is observed.
- With increase in  $\text{AgNO}_3$ :Ethanol conc. the Ag NPs density and growth rate increases also on larger diameter nanorods growth rate and hence density is higher.
- For increasing conc. of  $\text{AgNO}_3$ :Ethanol the resonant wavelength is observed to have a higher shift.
- Temperature variation profile due to the gas flow in PVT tube is studied in COMSOL.

# PLAN OF ACTION

Work	Sem1		Sem2		Sem3		Sem4	
	Q1	Q2	Q3	Q4	Q5	Q6	Q7	Q8
Experimental training and literature review about proposed topic								
Simulation								
Fabrication experiments								
Device fabrication and optimization								
Paper Writing								
Thesis Writing								

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THANK YOU !